NSN 5961-01-324-4910

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-324-4910 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.335 inches Overall Width: 1.050 inches **End Application:** Aircraft, b-2 bomber (atb); navstar global positioning system user equipment (ue) **Mounting Facility Quantity:** 2 Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes collector current, dc absolute all semiconductor device diode and 400.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No